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Atomic-Scale Perspective of Ultrafast Charge Transfer at a Dye–Semiconductor Interface

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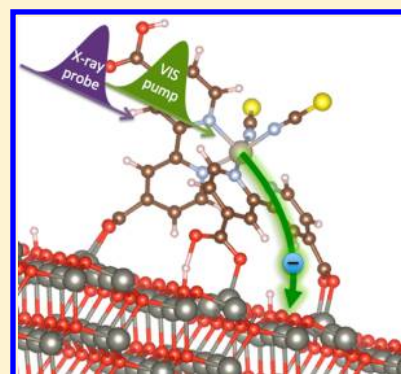
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Supporting Information

ABSTRACT: Understanding interfacial charge-transfer processes on the atomic level is crucial to support the rational design of energy-challenge relevant systems such as solar cells, batteries, and photocatalysts. A femtosecond time-resolved core-level photoelectron spectroscopy study is performed that probes the electronic structure of the interface between ruthenium-based N3 dye molecules and ZnO nanocrystals within the first picosecond after photoexcitation and from the unique perspective of the Ru reporter atom at the center of the dye. A transient chemical shift of the Ru 3d inner-shell photolines by (2.3 ± 0.2) eV to higher binding energies is observed 500 fs after photoexcitation of the dye. The experimental results are interpreted with the aid of ab initio calculations using constrained density functional theory. Strong indications for the formation of an interfacial charge-transfer state are presented, providing direct insight into a transient electronic configuration that may limit the efficiency of photoinduced free charge-carrier generation.

SECTION: Spectroscopy, Photochemistry, and Excited States



Interfacial charge-transfer dynamics play a crucial role in a number of emerging photoelectrochemical technologies, in particular, for photovoltaic and photocatalytic applications. An atomic level understanding of the transient electronic configurations that govern the conversion efficiencies of photoinduced excitations into separate charges is essential in order to exploit the full potential of novel photon-harvesting schemes. Dye-sensitized

solar cells (DSSCs) are a particularly prominent example of chemically engineered photovoltaic devices that convert sunlight into electricity through the combination of an efficient light absorber

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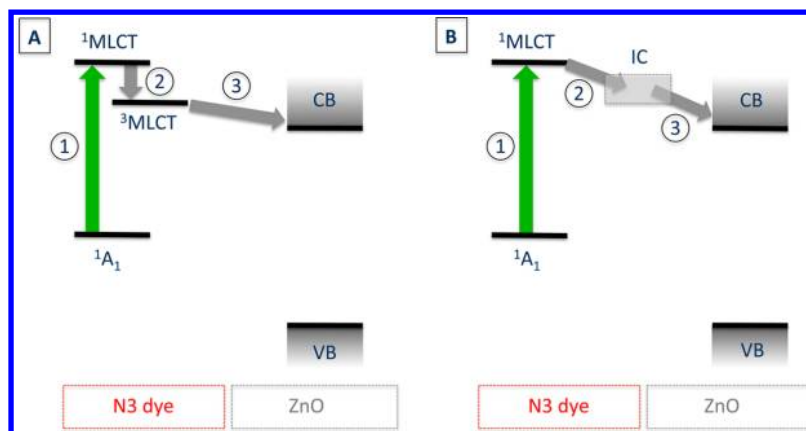


Figure 1. Two competing models for the sequence of charge-injection at N3 dye–ZnO nanocrystal interfaces after photoexcitation (step 1) of the dye. (A) Two-state injection model in which the electron is temporarily retained in a $^3\text{MLCT}$ state (step 2) on the dye molecule. (B) Intermediate interfacial state model in which the electron is temporarily retained in an interfacial complex (IC, step 2) at the dye–semiconductor interface. In both cases, step 3 indicates the release of the electron into the ZnO conduction band (CB) as a free charge carrier.

(dye molecules) with a nanostructured semiconductor substrate.^{1–4} Dye–semiconductor charge injection mechanisms have been investigated in numerous studies with a particular emphasis on the associated injection rates.^{5–22} However, owing to the complexity of the interfacial configurations, an unambiguous interpretation of the experimental findings is often challenging, in particular, on a level of detail commensurate with advanced theoretical predictions.^{3,23–26} Here a femtosecond time-resolved X-ray photoelectron spectroscopy (TRXPS^{27,28}) study is presented that probes the transient interfacial electronic configuration of the ruthenium-based dye N3 (bis(isothiocyanato)bis(2,2′-bipyridyl-4,4′-dicarboxylato)-ruthenium(II)) attached to a zinc oxide (ZnO) nanoparticle film within the first picosecond after photoexcitation of the dye. The atomic-site-specific TRXPS results in combination with density functional theory (DFT) calculations provide strong indications for a transient charge-transfer state that is established across the N3–ZnO interface within 500 fs. The findings are of direct relevance with respect to a decade-long controversy surrounding the fundamental electronic dynamics that underlie performance differences in TiO_2 - and ZnO-based DSSCs.

A number of studies have demonstrated that the differences between these systems, for example, in the critical photon-to-current conversion efficiencies cannot be explained by common system benchmarks such as the dye–semiconductor energy level alignment or the electron mobility of the substrate material.^{13,29,30} Instead, the atomic-scale electronic coupling and transient interfacial electronic structure are believed to play key roles in determining the device function.^{9–13,31} Ultrafast time-domain studies in the optical, infrared, and terahertz regimes have identified distinct differences between the dynamic response of dye–ZnO and dye– TiO_2 interfaces.^{5,8–13,17} In particular, transient signals from ZnO-based dye-sensitized systems are marked by prominent “slow” components, which evolve on time scales ranging from a few to hundreds of picoseconds. These response times are orders of magnitude longer than the typical sub-50 fs dynamics of TiO_2 -based interfaces and are, therefore, often associated with ZnO cell performance limitations.^{5,8–13} While these dramatic differences of time scales are consistently detected in a variety of experiments, their physical origin has long been a matter of debate, leading to two competing models for the underlying mechanisms (Figure 1).

In the two-state injection model^{5–7} (Figure 1A), only a small fraction of the initially excited singlet metal-to-ligand charge-transfer ($^1\text{MLCT}$) states directly injects an electron into the conduction

band (CB) of ZnO within <100 fs. The majority of dye molecules undergo intramolecular relaxation to the metastable $^3\text{MLCT}$ state owing to reduced electronic coupling between the dye and the semiconductor and a low density of charge accepting states in the substrate. Subsequent electron injection from the $^3\text{MLCT}$ state is suggested to take place on ~ 100 ps time scales; that is, the electrons are temporarily retained on the molecular dye.⁵ In the intermediate interfacial state model^{8–13} (Figure 1B), photoexcitation of the dye leads to fast (≤ 100 fs to ≤ 5 ps)^{8,10} formation of an interfacial complex (IC) at the dye–semiconductor interface with either neutral exciplex or ionic charge-transfer character.

Time-domain experiments suggest that the decay time scales of such an IC to release a mobile electron into the semiconductor substrate may range from ~ 2 to ~ 150 ps.^{8,10–13} Thus, in the intermediate interfacial state model, the electrons are temporarily retained at the interface between the dye and the substrate. While it is generally accepted that the increased retention time of the electrons either on the dye (Figure 1A) or at the dye–semiconductor interface (Figure 1B) will reduce the overall efficiency for free charge-carrier generation and therefore the device performance of ZnO-based photoelectrochemical devices, a clear identification of one of the mechanisms as the predominant electronic bottleneck has been hampered by the lack of a unique spectroscopic signature for either model.

The combination of femtosecond time-resolved inner-shell photoelectron spectroscopy with a detailed theoretical modeling presented here strongly supports the existence of a transient intermediate state located at the interface between the ZnO substrate and the N3 dye, which is populated within 500 fs after photoexcitation and has a lifetime well beyond 1 ps. The identification of the intermediate state character becomes possible through the unique capability of novel femtosecond X-ray spectroscopy techniques to monitor ultrafast local valence electron dynamics from the perspective of distinct atomic sites. Here the Ru metal center of the dye is chosen as a reporter atom during the interfacial charge-transfer process. In the experiment, N3-molecules adsorbed to a film of ZnO nanocrystals are excited by a 50 fs optical (535 nm) pump pulse. Interfacial charge-transfer dynamics are monitored by transient changes in femtosecond time-resolved XPS spectra. The measurements are performed at the Soft X-ray Materials Science (SXR) instrument of the Linac Coherent Light Source (LCLS) using <100 fs long

X-ray pulses at a photon energy of 850 eV. (See Supporting Information S2 for details.)

Femtosecond Time-Resolved X-ray Photoelectron Spectra. Figure 2A shows two photoelectron spectra in the binding energy range

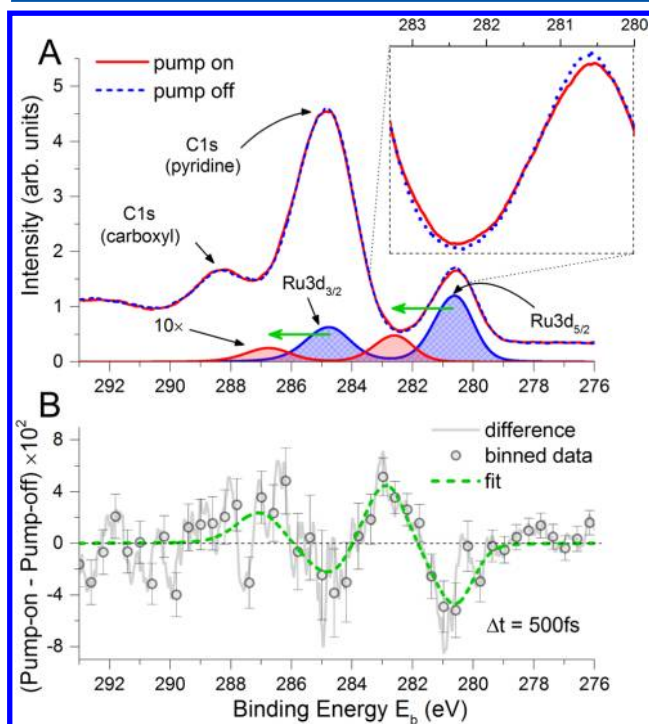


Figure 2. (A) Photoelectron spectra of N3/ZnO in the region of the C 1s and Ru 3d photolines recorded with (red, solid) and without (blue, dashed) the optical pump pulse preceding the X-ray probe pulse by 500 fs. The filled curves represent the Ru 3d_{3/2,5/2} doublet before (blue, cross-hatched) and after (red) photoexcitation of the dye. (B) Difference between pump-on and pump-off spectra at a pump–probe time delay of 500 fs (gray line). Circles correspond to the difference spectrum, rebinned to match the energy resolution of the experiment. Error bars indicate ± 1 standard deviation uncertainty ranges. The dashed green fit curve is based on a model that describes the entire spectral change by a transient chemical shift of the Ru 3d signal as indicated by the green arrows in panel A.

between $E_b = 276$ and 293 eV recorded with (red, solid) and without (blue, dashed) the optical pump pulse preceding the X-ray pulse by 500 fs. The photoelectron spectra are marked by three prominent peaks corresponding to the Ru 3d_{5/2} line ($E_b = 280.6$ eV) and two C 1s lines associated with carbon atoms in the

pyridine rings ($E_b = 284.8$ eV) and the carboxyl groups ($E_b = 288.3$ eV) of the dye.³²

The Ru 3d_{3/2} line ($E_b = 284.8$ eV) and the C 1s line from the thiocyanate groups ($E_b = 286.0$ eV, not shown) are covered by the much more intense pyridine C 1s peak.³² The inset (top, right) shows an enlarged section of the spectrum in the region of the Ru 3d_{3/2} line. The pump–pulse induces a decrease in the ground state Ru 3d_{3/2} signal (blue, dashed) and a complementary increase in signal at ~ 2 eV higher binding energies between the Ru 3d_{3/2} peak and the shoulder of the pyridine C 1s peak.

The pump–pulse-induced spectral change can be seen in more detail in Figure 2B, which shows the difference between the pump-on and pump-off spectra. The difference signal exhibits a local minimum at the position of the Ru 3d_{3/2} peak and a local maximum at a ~ 2 eV higher binding energy, replicating the trend from Figure 2A. A second minimum is located at the position of the Ru 3d_{5/2} peak and a second maximum at ~ 2 eV higher binding energies. This observation indicates that 500 fs after photoexcitation the fraction of molecules excited by the optical pump–pulse experiences an increase in effective binding energy E_b of both Ru 3d spin–orbit components on the order of ~ 2 eV.

The dashed green line in Figure 2B is the result of a fit based on the assumption that the excitation-induced difference between the pump-on and pump-off spectra can be described entirely by a transient chemical shift of the Ru 3d features. This results in a fit procedure with only two free parameters, the fraction F of the Ru 3d signal that exhibits the transient shift and the magnitude ΔE_b of the shift. An accurate description of the Ru 3d_{3/2,5/2} doublet (Figure 2A, blue and red filled curves) is derived from synchrotron measurements on a Ru(0001) crystal taking into account the natural line shapes and the instrumental response functions of the synchrotron- and the LCLS-based XPS spectrometers. (See S4.1 in the Supporting Information for details.) The good agreement of the fit with the data as illustrated in Figure 2B supports the ad-hoc imposed description of the difference signal by the transient shift of the Ru doublet, while other signals, such as the four times more intense C 1s signal from the pyridine group, contribute to a much smaller amount. A quantitative analysis of the absolute fit reliability is described in the SI (S4.2).

Least-square fits are performed for two data sets at pump–probe time delays of $\Delta t = 500$ fs and $\Delta t = 1$ ps (S4 in the Supporting Information). The central experimental findings of this study are (a) the Ru 3d doublet exhibits a transient chemical shift $\Delta E_b = (2.3 \pm 0.2)$ eV to higher binding energies 500 fs after photoexcitation of the dye, (b) the doublet exhibits a very similar chemical shift $\Delta E_b = (1.9 \pm 0.3)$ eV at 1 ps pump–probe delay, (c) possible photon-induced chemical shifts in the C 1s core

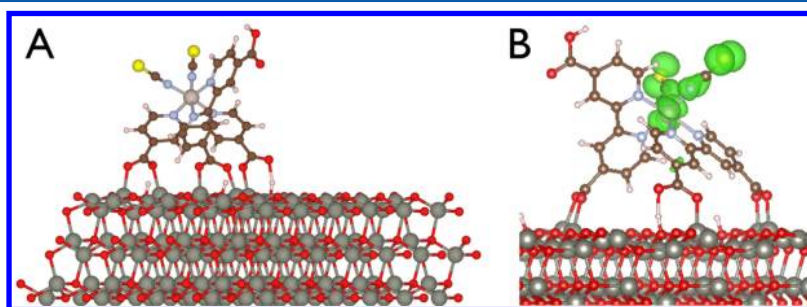


Figure 3. (A) Lowest energy adsorption geometry of N3 dye on wurtzite ZnO (10 $\bar{1}0$). (B) HOMO orbital of N3 dye concentrated on the central Ru atom and the thiocyanate ligands. The iso-surfaces mark an electron density of 5% relative to the maximum value. Note the different viewing angles in panels A and B for improved clarity.

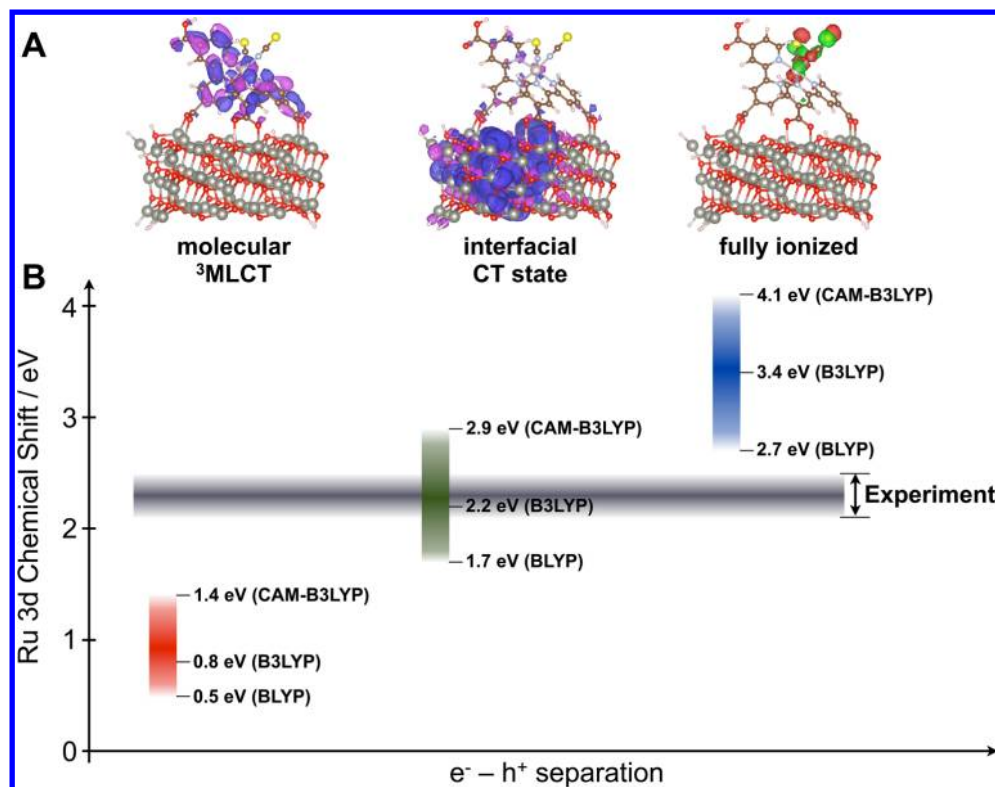


Figure 4. (A) Calculated electronic configurations for three limiting cases of transient electron–hole states (from left): molecular ³MLCT state, interfacial CT state, and fully ionized state. For the ³MLCT and CT states, the wave function of the excited electron is displayed, while for the fully ionized state the hole wave function is shown. (B) Calculated Ru 3d core level binding energy shifts obtained with three different functionals (BLYP, B3LYP, CAM-B3LYP). The gray band represents the experimentally determined shift of $\Delta E_b = (2.3 \pm 0.2)$ eV at a delay of 500 fs after photoexcitation of the dye.

levels are much less pronounced and below our detection limit. The dye excitation fractions derived by the fit procedure are $F = 4(\pm 1)\%$ and $F = 7(\pm 2)\%$ for pump–probe delays of 500 fs and 1 ps, respectively.

Modeling of the Interface. The experimental results are interpreted with the aid of first-principles DFT calculations.^{33,34} Figure 3A shows the lowest energy configuration of an N3 molecule adsorbed onto a wurtzite ZnO (10 $\bar{1}$ 0) surface modeled in a 2-D slab geometry. (See S5 in the Supporting Information for computational details.) In this configuration, the dye has three points of contact with the ZnO surface. Two of the four carboxyl groups are deprotonated and bound to the surface in a bidentate bridging mode. This picture is consistent with the results of a previous infrared spectroscopy study.³⁵ The detached protons passivate two nearby oxygen atoms of the ZnO surface. In addition, one carboxyl group coordinates via an O–Zn and an H–O interaction to the surface. This molecular conformation is found to be at least ~ 1.3 eV more favorable in energy than any other adsorption geometry. Figure 3B shows the highest occupied molecular orbital (HOMO) of N3 attached to ZnO (10 $\bar{1}$ 0). The strong concentration of the HOMO on the central Ru atom and the thiocyanate ligands is consistent with previous experimental and theoretical studies.^{18,19,23,24,32,36}

In an intuitive picture, the photoinduced removal of an electron from the HOMO of the dye molecule is expected to lead to a significant increase in inner-shell binding energies in those parts of the molecule where most of the HOMO electron density is localized. This is consistent with our experimental finding that the excitation-induced chemical shift is much more prominent in the Ru 3d doublet than in the C 1s carboxyl and pyridine signals.

A transient chemical shift of the C 1s lines associated with the thiocyanate ligands cannot be ruled out, but it is challenging to detect its contribution to the overall signal due to the spectral overlap with the more intense carbon and ruthenium signals in the vicinity of ~ 286 eV binding energy.³²

The goal of the theoretical analysis is to identify a length-scale of charge separation between the optically excited electron and hole densities that is consistent with the observed transient core-level shift ΔE_b . Valence excited electronic configurations and associated ΔE_b are calculated employing a constrained density functional theory (CDFT)³⁷ formalism and a finite cluster model of the N3/ZnO interfacial structure described above (see S5 for details).

Three limiting cases of transient electronic configurations are shown in Figure 4A: an intramolecular ³MLCT state, an interfacial CT state, and a fully ionized dye adsorbed on a neutral ZnO substrate. In the ³MLCT state, the excited electron is mostly located on the bipyridine ligands, which is consistent with recent calculations for solvated N3 molecules.¹⁸ In the fully ionized configuration, the hole density largely mimics the HOMO of the ground-state molecule (Figure 3B), while the electron is assumed to be completely removed from the system. The electronic charge distribution of the interfacial CT state is constrained to simulate a configuration in which the excited electron is transferred to the ZnO substrate but not yet further separated from the dye cation. This configuration represents a charge-separation length scale that is intermediate to the ³MLCT and the fully ionized configurations. In contrast with the fully ionized state, the ³MLCT and interfacial CT states represent electronic excited states that require an additional constraining

potential to be modeled in a DFT framework. As outlined in the SI (S5.4), this is facilitated by the CDFT approach.

The central finding of the theoretical analysis is summarized in Figure 4B. For each of the limiting electronic configurations depicted in Figure 4A, the chemical shift of the Ru 3d lines compared with the neutral ground state is estimated using three different DFT functionals (BLYP,^{38,39} B3LYP,^{40,41} CAM-B3LYP⁴²).

These functionals span a wide range in their description of electronic screening (see S5.3 in the Supporting Information), leading to correspondingly wide ranges of estimated chemical shifts as signified by vertical colored bands. All chemical shifts increase consistently in the order BLYP, B3LYP, and CAM-B3LYP, consistent with the decrease in electronic screening effects along this sequence of functionals. The vertical bands in Figure 4B can therefore be interpreted as conservative uncertainty ranges of the DFT calculations. The gray band indicates the measured chemical shift (including the experimental uncertainty range) of the Ru 3d_{3/2,5/2} doublet 500 fs after photoexcitation of the dye.

The comparison between theory and experiment strongly favors the interfacial charge-transfer complex as the predominant electronic configuration during the early stages of the electron injection process. The similarity of chemical shifts measured at both time delays, 500 fs and 1 ps, indicates that the interfacial CT state has a lifetime significantly beyond 1 ps. This is in agreement with previous experimental findings on the decay time scales for the intermediate IC, which range from ~2 to ~150 ps.^{8,10–13} The gap between the experimental findings (gray) and the theoretical uncertainty range for the fully ionized dye configuration (blue) in Figure 4B confirms the common notion that the charge injection process in the N3-ZnO system is relatively slow; that is, it proceeds on, at least, picosecond time scales. This long-lived intermediate state very likely contributes to the weak performance of ZnO-based DSSCs compared with TiO₂-based systems, as it increases the relative yield of unwanted loss processes such as electron–hole recombination. In contrast, for N3-TiO₂ and similar TiO₂-based systems, the injected electron becomes available as a free charge carrier on a sub-50 femtosecond time scale.^{14–16}

The electronic configurations shown in Figure 4A and, in particular, the CDFT-based description of the interfacial CT state are model systems that represent distinct limiting cases of average electron–hole separation length scales. Further studies are needed to refine the exact nature of the intermediate state and to identify its physical origin. The estimated chemical shifts, however, are fairly insensitive to these details and vary predominantly with the average electron–hole distance. This supports the conclusion that the rate-limiting step for photoinduced free charge carrier generation at the N3/ZnO interface is characterized by an electronic configuration in which the electron has separated from the dye molecule but is still residing in close proximity to the dye cation at the dye/semiconductor interface. We note that a recent picosecond time-resolved X-ray absorption study lent support to the existence of intermediate interfacial charge-transfer complexes in solvated dye-sensitized TiO₂ nanocrystals based on the detection of surface trap states.²²

The combined experimental and theoretical study presented here highlights the potential of TRXPS to monitor transient interfacial electron configurations with femtosecond time resolution and on an atomic level of detail. The novel method complements existing techniques such as time-resolved X-ray absorption and provides, in particular, exquisite surface sensitivity to monitor

interfacial charge dynamics on application-like electrode configurations. Because of the moderate peak-power requirements of XPS, the technique will take full advantage of next-generation free-electron lasers (FELs) such as LCLS-II and the European XFEL, which will operate at significantly higher pulse repetition rates compared with existing ultrafast X-ray light sources.

EXPERIMENTAL AND COMPUTATIONAL METHODS

Sample Preparation. ZnO nanoparticles were synthesized by adding 50 mmol tetramethylammonium hydroxide (25% solution in methanol from Sigma-Aldrich) to a suspension of 50 mmol zinc acetate dihydrate (Merck) in 100 mL of anhydrous ethanol (Sigma-Aldrich). Extra solvent was decanted and ZnO particles were washed with ethanol. Thin films were obtained by spin coating 0.20 mL of the ZnO suspension on a Si(100) substrate, followed by drying and sintering in air. After ozone/UV cleaning, the thin films were immersed in 0.2 mM solution of N3 Ru dye (Aldrich) in absolute ethanol for 24 h. The resulting dye sensitized films were then thoroughly rinsed with ethanol, dried in an air stream, and stored in the dark. Details of the sample preparation and characterization of photon-induced sample damage are provided in the SI (S1, S3).

Time-Resolved XPS Experiment. The experiment was performed at the Soft X-ray Materials Science (SXR) instrument of the Linac Coherent Light Source (LCLS). An ultrashort (fwhm ≤ 50 fs) laser pulse with a center wavelength of 535 nm electronically excited the ruthenium dye complex. The transient electronic structure was probed by a time-delayed X-ray pulse (fwhm ≤ 100 fs) centered at 850 eV using a monochromator. Femtosecond time-resolved inner shell photoelectron spectra were recorded with a hemispherical electron analyzer (Scienta R3000). The uncertainty in the pump–probe time-delay Δt was ~ 280 fs (fwhm). The pump laser was operated at 60 Hz, which is half the repetition rate of the LCLS (120 Hz), enabling the simultaneous recording of pump-on and pump-off spectra, which strongly suppresses the impact of experimental drifts on the pump-on/pump-off difference spectra. A detailed description of the experiment and data analysis is given in the SI (S2–S4).

Theoretical Modeling by Constrained Density Functional Theory. Structural optimizations were performed using plane-wave pseudopotential-based DFT^{33,34} as implemented in the VASP⁴³ package. A plane-wave cutoff of 350 eV and pseudopotentials with the following valence electronic configurations were employed: Zn(3d¹⁰4s²), O(2s²2p⁴), C(2s²2p²), N(2s²2p³), S(3s²3p⁴), H(1s¹), Ru(5s¹4d⁷). Exchange-correlation effects were modeled using the Perdew–Burke–Ernzerhoff⁴⁴ form of the generalized gradient approximation. The Brillouin zone was sampled at the Γ point. Structures were optimized until all forces were < 0.04 eV/Å. Excited-state energies and associated core-level shifts (ΔE_b) were calculated through CDFT,³⁷ as implemented in the NWChem code,⁴⁵ using three different DFT functionals: BLYP,^{38,39} B3LYP,^{40,41} and CAM-B3LYP.⁴² Ru was modeled using the Sapporo-DZP-2012⁴⁶ all-electron basis set, while N, C, S, Zn, and O were modeled using the SBKJC^{47,48} basis set and associated effective core potential (ECP). H was described through the 6-311+G* basis set. Ru 3d core-level shifts were estimated using the initial state rule as differences in core-level eigenvalues of ground and valence excited states. Further details are provided in the SI (S5).

■ ASSOCIATED CONTENT

● Supporting Information

S1. Sample preparation, S2. Time-resolved XPS experiment, S3. Sample damage measurements and control, S4. Data analysis, S5. Theoretical modeling by constrained density functional theory (CDFT). This material is available free of charge via the Internet at <http://pubs.acs.org>.

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Notes

The authors declare no competing financial interest.

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